

1. Start Substrate Wafer



2. Deposit Masking Material



3. Pattern Masking Material



4. Etch Substrate Wafer

FIG. 1 PRIOR ART MICROFABRICATION PROCESS



(a) Starting SOI wafer



(b) Mesa Etch



(c) Structural Etch

FIG. 2 FI

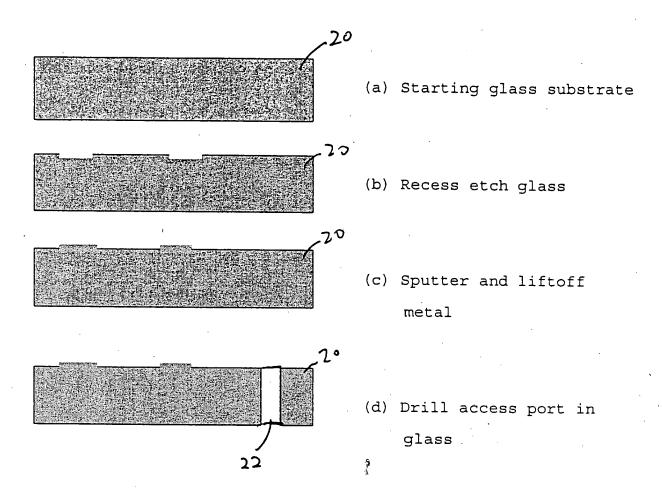


FIG. 3 PROCESS STEPS FOR GLASS SUBSTRATE

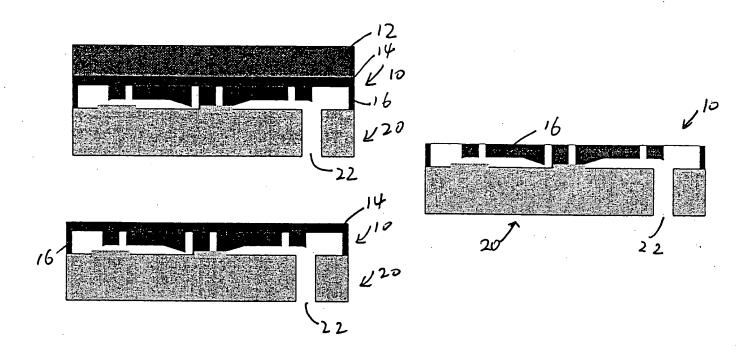


FIG. 4
BONDING, WAFER THINNING AND OXIDE DIELECTRIC REMOVAL

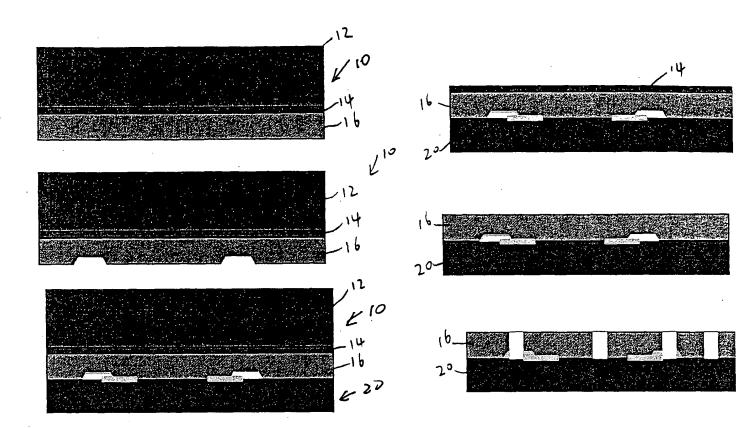


FIG. 5 BASELINE BESOI PROCESS SEQUENCE.

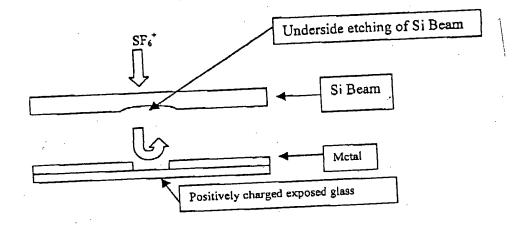
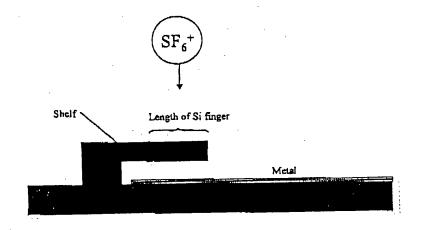
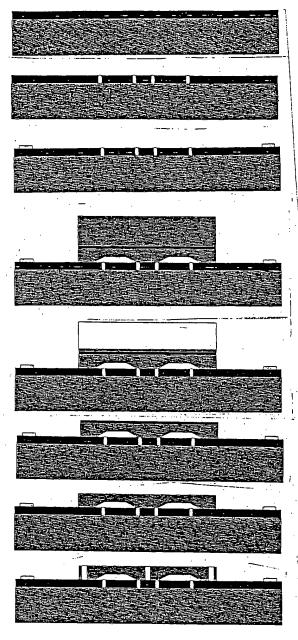


FIG. 6A (PRIOR ART)



F16.6B



AG.7

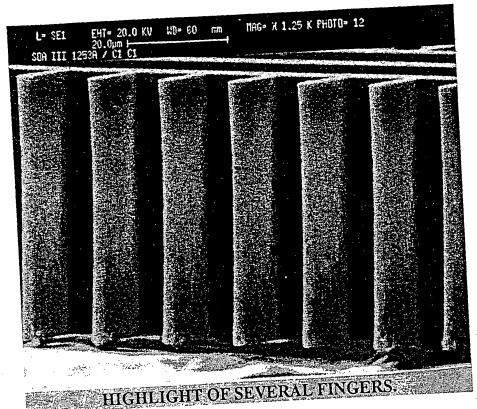


FIG. 8

(a) EPITAXIAL COMB FINGERS.

(a) BASELINE BESOI COMB FINGERS

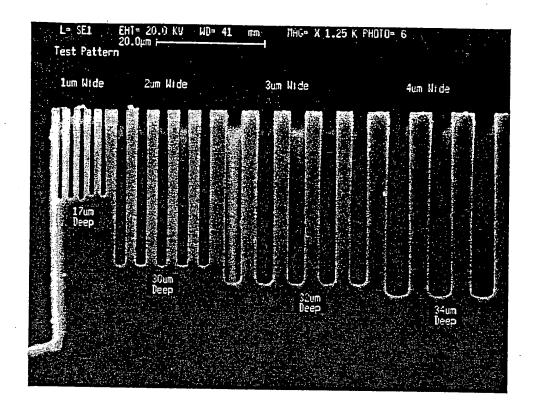


FIG. 9 PHENOMENON OF RIE LAG, WHERE NARROW TRENCHES ETCH MORE SLOWLY